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MCP1703A

250 mA, 16V, Low Quiescent Current LDO Regulator

Features

- Passes Automotive AEC-Q100 Reliability Testing
- Reduced Ground Current During Dropout
- Faster Startup Time
- 2.0 µA Typical Quiescent Current
- Input Operating Voltage Range: 2.7V to16.0V
- 250 mA Output Current for Output Voltages ≥ 2.5V
- 200 mA Output Current for Output Voltages < 2.5V
- Low Dropout Voltage, 625 mV Typical @ 250 mA for V_R = 2.8V
- 0.4% Typical Output Voltage Tolerance
- Standard Output Voltage Options:
  - 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.3V, 4.0V, 5.0V
- Output Voltage Range: 1.2V to 5.5V in 0.1V Increments (50 mV increments available upon request)
- A/D Friendly Voltage Options: 2.05V, 3.07V, 4.1V
- Stable with 1.0 µF to 22 µF Ceramic Output Capacitance
- Short-Circuit Protection
- Overtemperature Protection

Applications:

- Battery-Powered Devices
- Battery-Powered Alarm Circuits
- Smoke Detectors
- CO_2 Detectors
- Pagers and Cellular Phones
- Smart Battery Packs
- Low Quiescent Current Voltage Reference
- PDAs
- Digital Cameras
- Microcontroller Power
- Solar-Powered Instruments
- Consumer Products

Related Literature:

- AN765, "*Using Microchip's Micropower LDOs*", DS00765, Microchip Technology Inc., 2007
- AN766, "*Pin-Compatible CMOS Upgrades to Bipolar LDOs*", DS00766, Microchip Technology Inc., 2003
- AN792, "*A Method to Determine How Much Power a SOT23 Can Dissipate in an Application*", DS00792, Microchip Technology Inc., 2001

Description

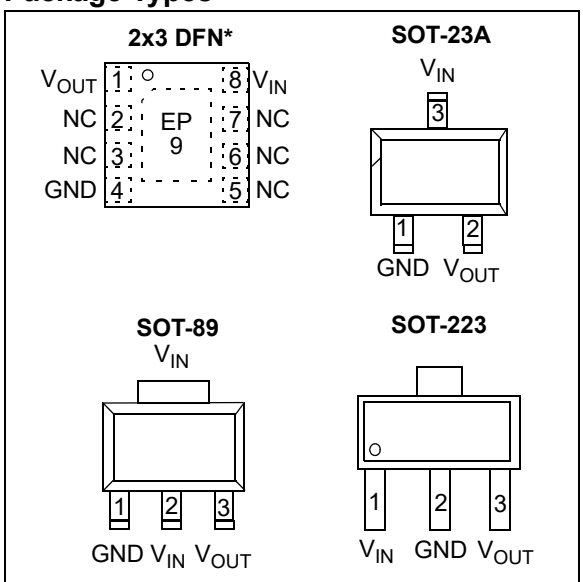
The MCP1703A is an improved version of the MCP1703 low dropout (LDO) voltage regulator that can deliver up to 250 mA of current while consuming only 2.0 µA of quiescent current (typical). The input operating range is specified from 2.7V to 16.0V, making it an ideal choice for two to six primary cell battery-powered applications, 9V alkaline and one or two-cell Li-Ion-powered applications.

The MCP1703A is capable of delivering 250 mA with only 625 mV (typical) of input to output voltage differential (V_{OUT} = 2.8V). The output voltage tolerance of the MCP1703A is typically ±0.4% at +25°C and ±3% maximum over the operating junction temperature range of -40°C to +125°C. Line regulation is ±0.1% typical at +25°C.

Output voltages available for the MCP1703A range from 1.2V to 5.5V. The LDO output is stable when using only 1 µF of output capacitance. Ceramic, tantalum or aluminum electrolytic capacitors can all be used for input and output. Overcurrent limit and overtemperature shutdown provide a robust solution for any application. Package options include the SOT-223-3, SOT-23A, 2x3 DFN-8 and SOT-89-3.

The MCP1703A is AEC-Q100 qualified for automotive applications.

Package Types

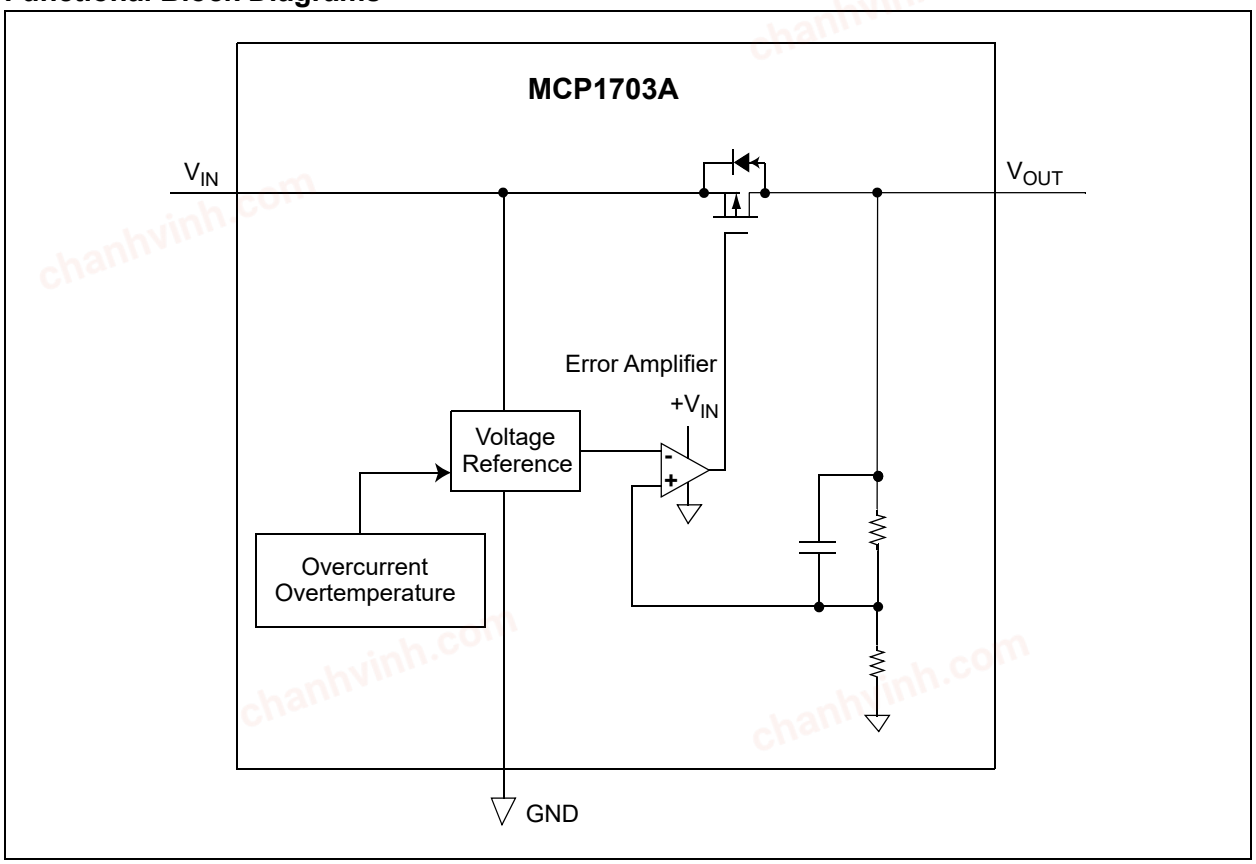


* Includes Exposed Thermal Pad (EP); see Table 3-1.

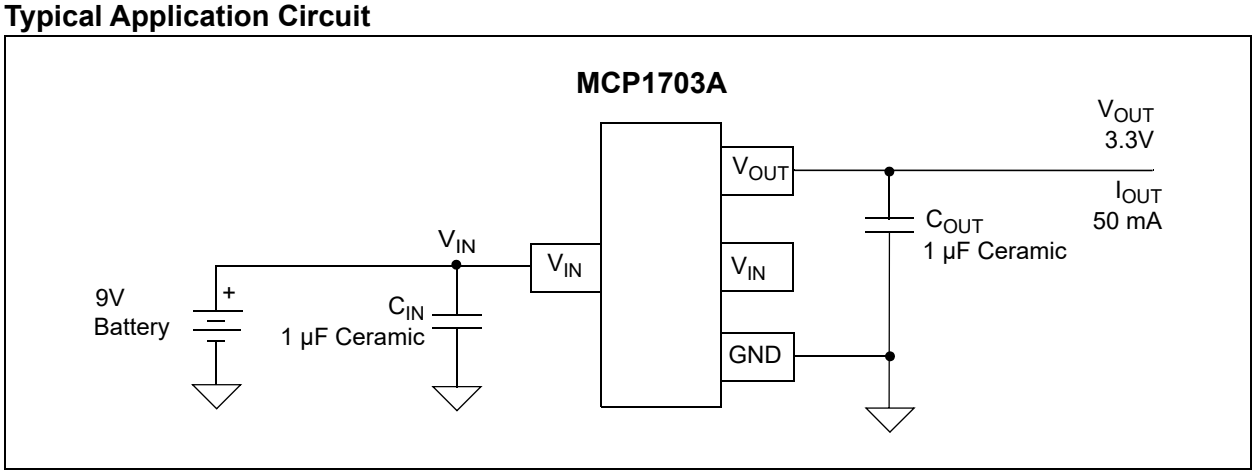
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Functional Block Diagrams



Typical Application Circuit



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1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V_{DD} ..... +18V
All Inputs and Outputs w.r.t. ..... (V_{SS} – 0.3V) to (V_{IN} + 0.3V)
Peak Output Current ..... 500 mA
Storage Temperature ..... -65°C to +150°C
Maximum Junction Temperature ..... +150°C
ESD Protection on all Pins
HBM ..... ≥ 4 kV
MM ..... ≥ 400V
CDM (SOT-223) ..... ≥ 1 kV

† **Notice:** Stresses above those listed under “Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, all limits are established for $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$, **Note 1**, I_{LOAD} = 1 mA, C_{OUT} = 1 µF (X7R), C_{IN} = 1 µF (X7R), T_A = +25°C.
Boldface type applies for junction temperatures, T_J **(Note 7)** of -40°C to +125°C.

Parameters	Symbol	Min	Typ	Max	Units	Conditions
Input / Output Characteristics						
Input Operating Voltage	V_{IN}	**2.7**	—	**16.0**	V	**Note 1**
Input Quiescent Current	I_q	—	2.0	**5**	µA	I_L = 0 mA
Maximum Output Current	I_{OUT}	**250**	—	—	mA	For $V_R \geq 2.5V$
		50	100	—	mA	For $V_R < 2.5V$, $V_{IN} \geq 2.7V$
		100	130	—	mA	For $V_R < 2.5V$, $V_{IN} \geq 2.95V$
		150	200	—	mA	For $V_R < 2.5V$, $V_{IN} \geq 3.2V$
		200	230	—	mA	For $V_R < 2.5V$, $V_{IN} \geq 3.45V$
Output Short Circuit Current	I_{OUT_SC}	—	400	—	mA	$V_{IN} = V_{IN(MIN)}$ **(Note 1)**, V_{OUT} = GND, Current (average current) measured 10 ms after short is applied.
Output Voltage Regulation	V_{OUT}	**V_R–3.0%**	V_R±0.4%	**V_R+3.0%**	V	**Note 2**
		V_R–2.0%	V_R±0.4%	V_R+2.0%	V	
		V_R–1.0%	V_R±0.4%	V_R+1.0%	V	1% Custom

Note 1: The minimum V_{IN} must meet two conditions: $V_{IN} \geq 2.7V$ and $V_{IN} \geq (V_{OUT(MAX)} + V_{DROPOUT(MAX)})$.
2: V_R is the nominal regulator output voltage. For example: V_R = 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.3V, 4.0V or 5.0V. The input voltage $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or Vi_{IN} = 2.7V (whichever is greater); I_{OUT} = 100 µA.
3: $TCV_{OUT} = (V_{OUT-HIGH} – V_{OUT-LOW}) \times 10^6/(V_R \times \Delta Temperature)$, $V_{OUT-HIGH}$ = highest voltage measured over the temperature range. $V_{OUT-LOW}$ = lowest voltage measured over the temperature range.
4: Load regulation is measured at a constant junction temperature using low duty cycle pulse testing. Changes in output voltage due to heating effects are determined using thermal regulation specification TCV_{OUT}.
5: Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its measured value with an applied input voltage of $V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.
6: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, q_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum 150°C rating. Sustained junction temperatures above 150°C can impact the device reliability.
7: The junction temperature is approximated by soaking the device under test at an ambient temperature equal to the desired junction temperature. The test time is small enough such that the rise in the junction temperature over the ambient temperature is not significant.

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DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise specified, all limits are established for $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$, **Note 1**, I_{LOAD} = 1 mA, C_{OUT} = 1 µF (X7R), C_{IN} = 1 µF (X7R), T_A = +25°C.
Boldface type applies for junction temperatures, T_J **(Note 7)** of -40°C to +125°C.

Parameters	Symbol	Min	Typ	Max	Units	Conditions
V_{OUT} Temperature Coefficient	TCV_{OUT}	—	65	—	ppm/°C	**Note 3**
Line Regulation	$DV_{OUT}/(V_{OUT} x \Delta V_{IN})$	–0.3	±0.1	+0.3	%/V	$(V_{OUT(MAX)} + V_{DROPOUT(MAX)}) \leq V_{IN} \leq 16V$, **Note 1**
Load Regulation	$\Delta V_{OUT}/V_{OUT}$	**-2.5**	±1.0	**+2.5**	%	I_L = 1.0 mA to 250 mA for $V_R \geq 2.5V$ I_L = 1.0 mA to 200 mA for $V_R < 2.5V$ V_{IN} = 3.65V, **Note 4**
Dropout Voltage **Note 1**, **Note 5**	$V_{DROPOUT}$	—	330	**650**	mV	I_L = 250 mA, V_R = 5.0V
		—	525	**725**	mV	I_L = 250 mA, 3.3V $\leq V_R < 5.0V$
		—	625	**975**	mV	I_L = 250 mA, 2.8V $\leq V_R < 3.3V$
		—	750	**1100**	mV	I_L = 250 mA, 2.5V $\leq V_R < 2.8V$
		—	—	—	mV	$V_R < 2.5V$, See Maximum Output Current Parameter
Output Delay Time	T_{DELAY}	—	600	—	µs	V_{IN} = 0V to 6V, V_{OUT} = 90% V_R, R_L = 50Ω resistive
Output Noise	e_N	—	1		$\mu V/(Hz)^{1/2}$	I_L = 50 mA, f = 1 kHz, C_{OUT} = 1 µF
Power Supply Ripple Rejection Ratio	PSRR	—	35	—	dB	f = 100 Hz, C_{OUT} = 1 µF, I_L = 10 mA, V_{INAC} = 200 mV pk-pk, C_{IN} = 0 µF, V_R = 5.0V
Thermal Shutdown Protection	T_{SD}	—	150	—	°C	

Note 1: The minimum V_{IN} must meet two conditions: $V_{IN} \geq 2.7V$ and $V_{IN} \geq (V_{OUT(MAX)} + V_{DROPOUT(MAX)})$.

2: V_R is the nominal regulator output voltage. For example: V_R = 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V, 3.3V, 4.0V or 5.0V. The input voltage $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or Vi_{IN} = 2.7V (whichever is greater); I_{OUT} = 100 µA.

3: $TCV_{OUT} = (V_{OUT-HIGH} – V_{OUT-LOW}) \times 10^6/(V_R \times \Delta Temperature)$, $V_{OUT-HIGH}$ = highest voltage measured over the temperature range. $V_{OUT-LOW}$ = lowest voltage measured over the temperature range.

4: Load regulation is measured at a constant junction temperature using low duty cycle pulse testing. Changes in output voltage due to heating effects are determined using thermal regulation specification TCV_{OUT}.

5: Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its measured value with an applied input voltage of $V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

6: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, q_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum 150°C rating. Sustained junction temperatures above 150°C can impact the device reliability.

7: The junction temperature is approximated by soaking the device under test at an ambient temperature equal to the desired junction temperature. The test time is small enough such that the rise in the junction temperature over the ambient temperature is not significant.

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TEMPERATURE SPECIFICATIONS(1)

Parameters	Sym	Min	Typ	Max	Units	Conditions
Temperature Ranges						
Operating Junction Temperature Range	T_J	-40	—	+125	°C	Steady State
Maximum Junction Temperature	T_J	—	—	+150	°C	Transient
Storage Temperature Range	T_A	-65	—	+150	°C	
Thermal Package Resistance (Note 2)						
Thermal Resistance, 3-Lead SOT-223	θ_{JA} θ_{JC}	— —	62 15	— —	°C/W	EIA/JEDEC JESD51-7 FR-4 0.063 4-Layer Board
Thermal Resistance, 3-Lead SOT-23A	θ_{JA} θ_{JC}	— —	336 110	— —	°C/W	EIA/JEDEC JESD51-7 FR-4 0.063 4-Layer Board
Thermal Resistance, 3-Lead SOT-89	θ_{JA} θ_{JC}	— —	180 52	— —	°C/W	EIA/JEDEC JESD51-7 FR-4 0.063 4-Layer Board
Thermal Resistance, 8-Lead 2x3 DFN	θ_{JA} θ_{JC}	— —	70 13.4	— —	°C/W	EIA/JEDEC JESD51-7 FR-4 0.063 4-Layer Board

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum 150°C rating. Sustained junction temperatures above 150°C can impact the device reliability.

2: Thermal Resistance values are subject to change. Please visit the Microchip web site for the latest packaging information.

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2.0 TYPICAL PERFORMANCE CURVES

Note:	The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated: C_{OUT} = 1 µF Ceramic (X7R), C_{IN} = 1 µF Ceramic (X7R), I_L = 1 mA, T_A = +25°C, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

Note: Junction Temperature (T_J) is approximated by soaking the device under test to an ambient temperature equal to the desired junction temperature. The test time is small enough such that the rise in Junction temperature over the Ambient temperature is not significant.

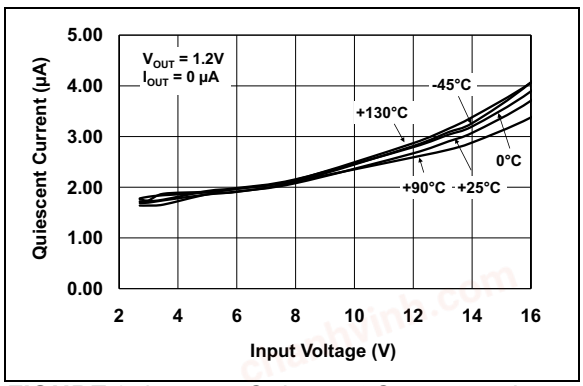


FIGURE 2-1: *Quiescent Current vs. Input Voltage.*

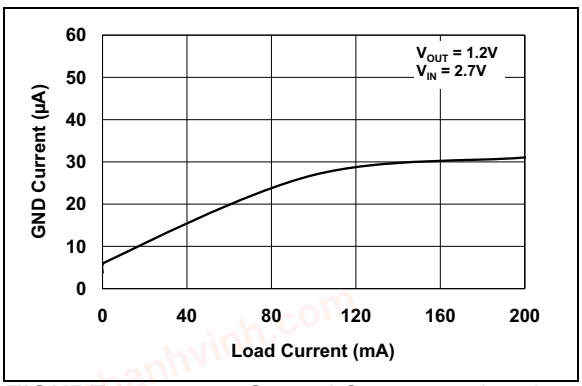


FIGURE 2-4: *Ground Current vs. Load Current.*

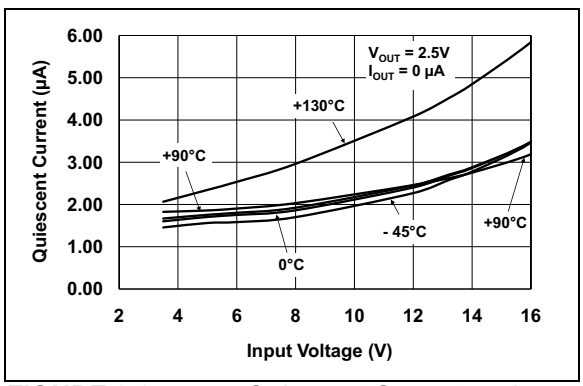


FIGURE 2-2: *Quiescent Current vs. Input Voltage.*

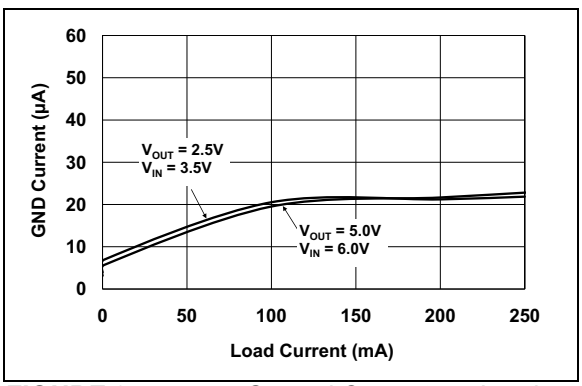


FIGURE 2-5: *Ground Current vs. Load Current.*

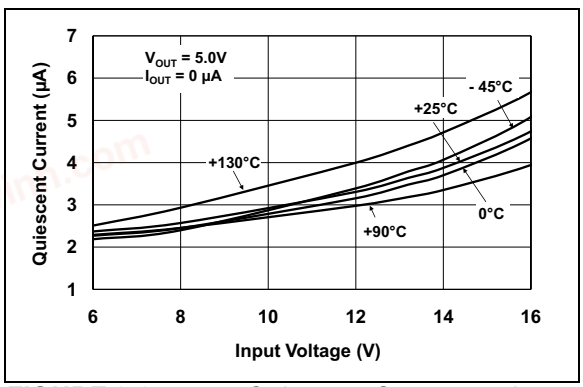


FIGURE 2-3: *Quiescent Current vs. Input Voltage.*

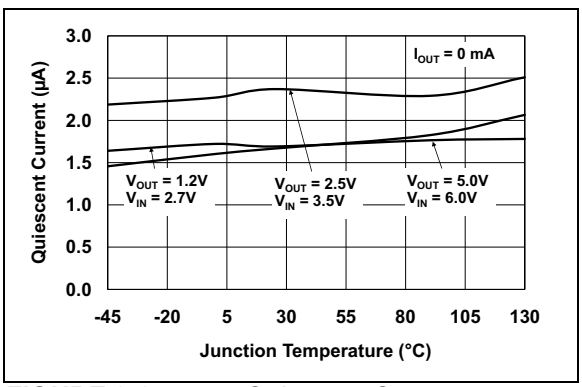


FIGURE 2-6: *Quiescent Current vs. Junction Temperature.*

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Note: Unless otherwise indicated: C_{OUT} = 1 µF Ceramic (X7R), C_{IN} = 1 µF Ceramic (X7R), I_L = 1 mA, T_A = +25°C, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

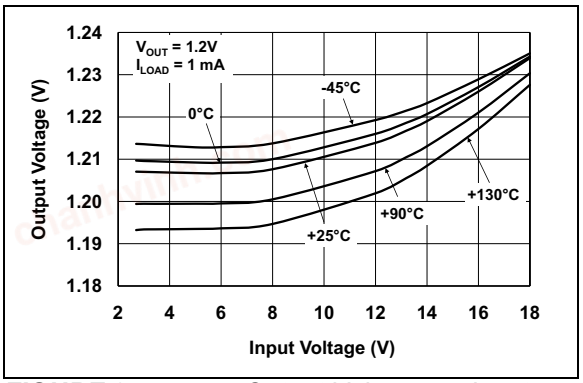


FIGURE 2-7: *Output Voltage vs. Input Voltage.*

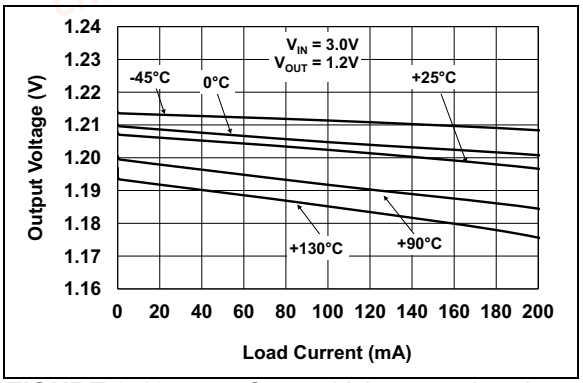


FIGURE 2-10: *Output Voltage vs. Load Current.*

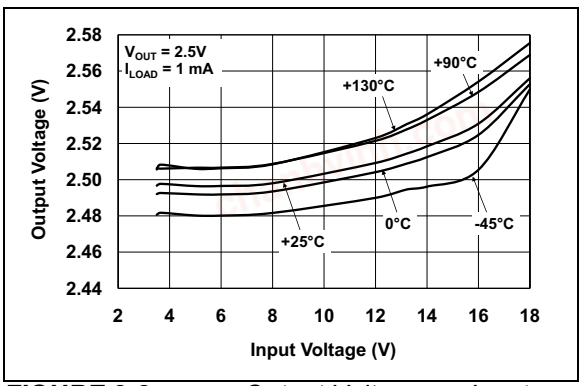


FIGURE 2-8: *Output Voltage vs. Input Voltage.*

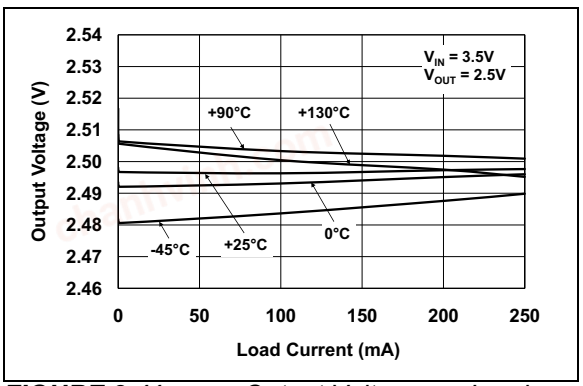


FIGURE 2-11: *Output Voltage vs. Load Current.*

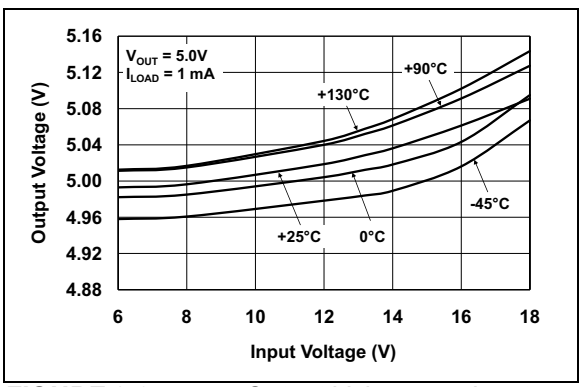


FIGURE 2-9: *Output Voltage vs. Input Voltage.*

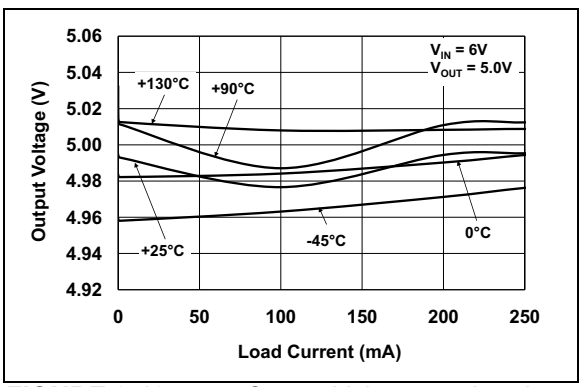


FIGURE 2-12: *Output Voltage vs. Load Current.*

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Note: Unless otherwise indicated: C_{OUT} = 1 µF Ceramic (X7R), C_{IN} = 1 µF Ceramic (X7R), I_L = 1 mA, T_A = +25°C, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

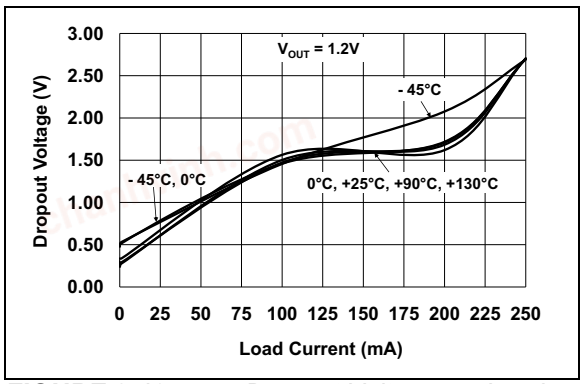


FIGURE 2-13: *Dropout Voltage vs. Load Current.*

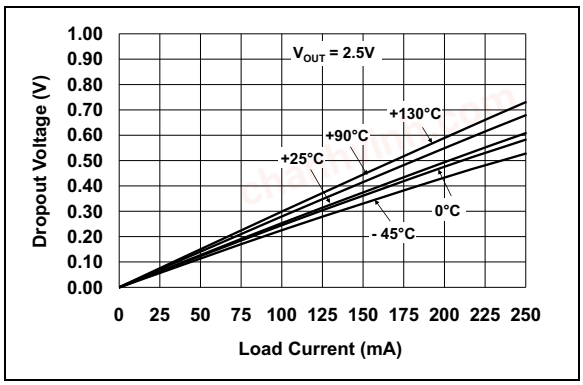


FIGURE 2-14: *Dropout Voltage vs. Load Current.*

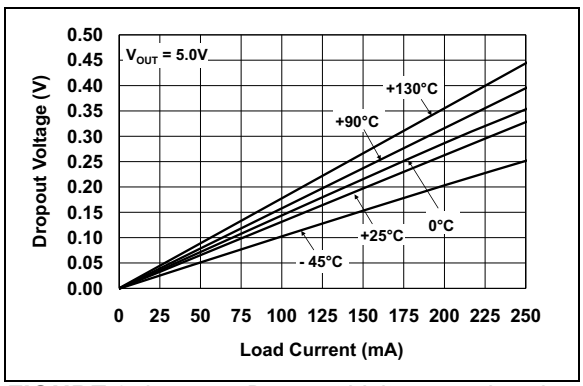


FIGURE 2-15: *Dropout Voltage vs. Load Current.*

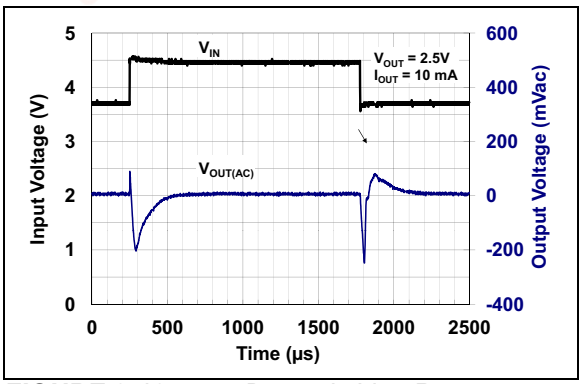


FIGURE 2-16: *Dynamic Line Response.*

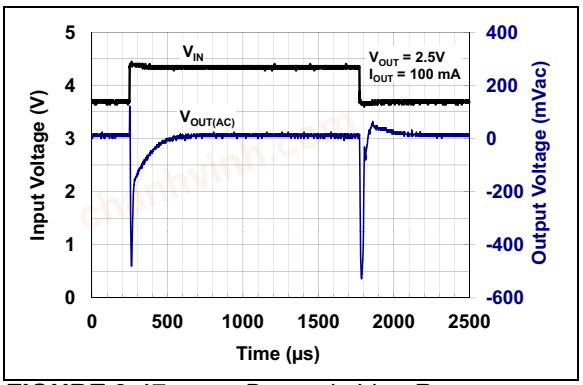


FIGURE 2-17: *Dynamic Line Response.*

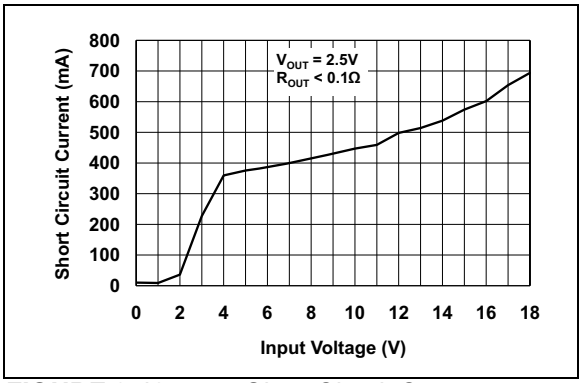


FIGURE 2-18: *Short Circuit Current vs. Input Voltage.*

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Note: Unless otherwise indicated: C_{OUT} = 1 µF Ceramic (X7R), C_{IN} = 1 µF Ceramic (X7R), I_L = 1 mA, T_A = +25°C, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

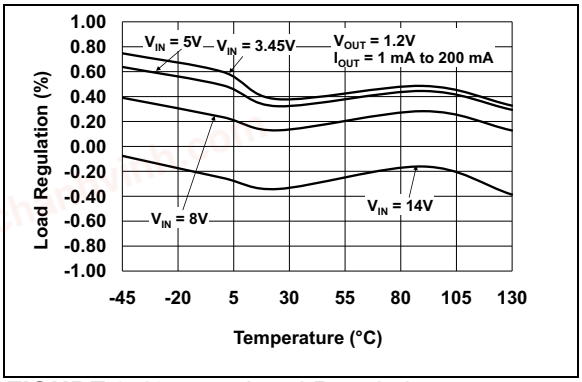


FIGURE 2-19: *Load Regulation vs. Temperature.*

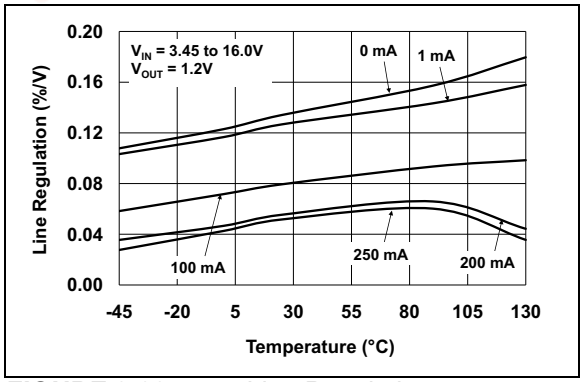


FIGURE 2-22: *Line Regulation vs. Temperature.*

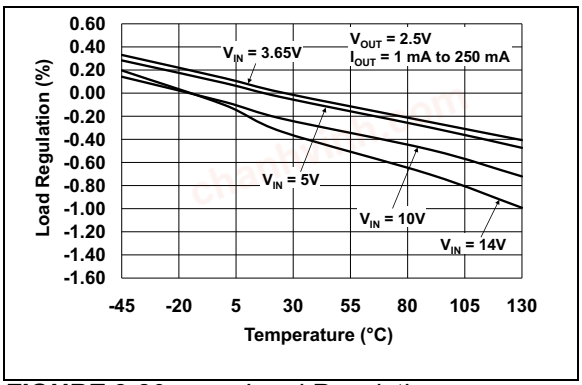


FIGURE 2-20: *Load Regulation vs. Temperature.*

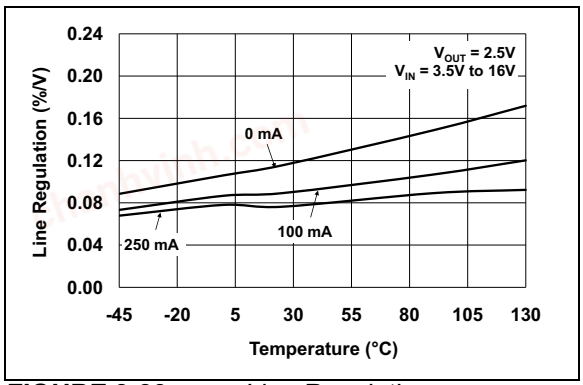


FIGURE 2-23: *Line Regulation vs. Temperature.*

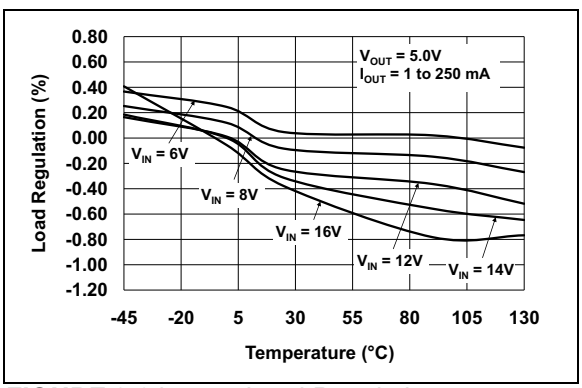


FIGURE 2-21: *Load Regulation vs. Temperature.*

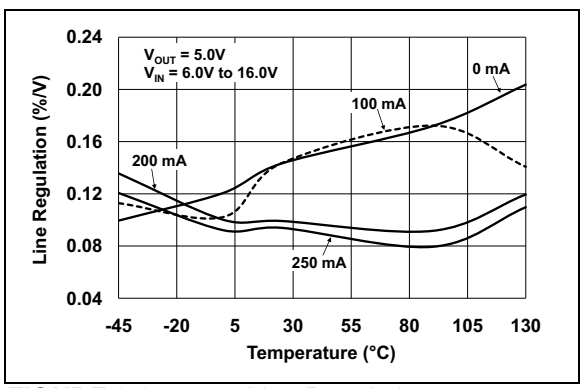


FIGURE 2-24: *Line Regulation vs. Temperature.*

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Note: Unless otherwise indicated: C_{OUT} = 1 µF Ceramic (X7R), C_{IN} = 1 µF Ceramic (X7R), I_L = 1 mA, T_A = +25°C, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

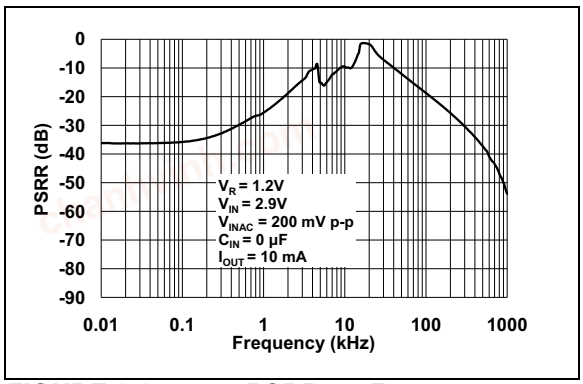


FIGURE 2-25: *PSRR vs. Frequency.*

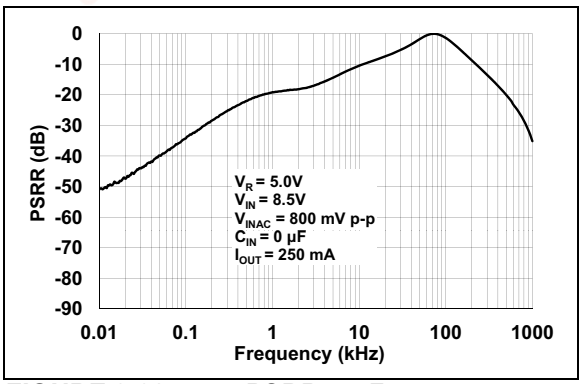


FIGURE 2-28: *PSRR vs. Frequency.*

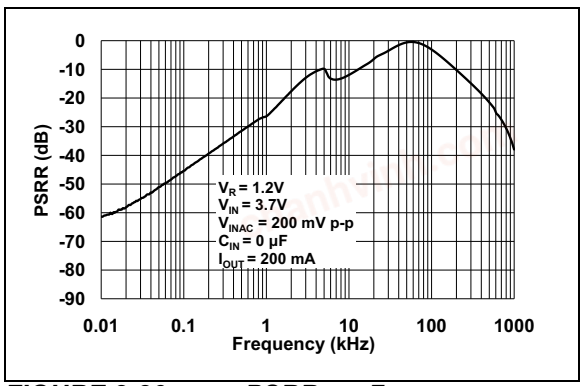


FIGURE 2-26: *PSRR vs. Frequency.*

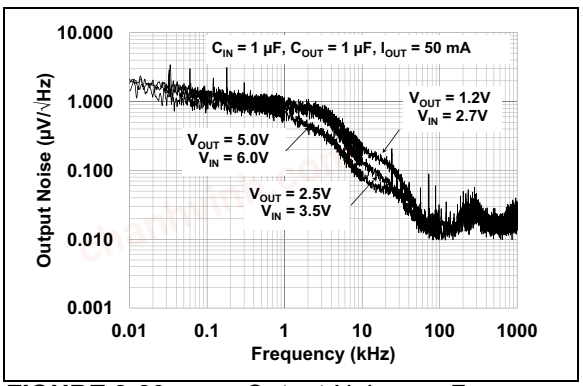


FIGURE 2-29: *Output Noise vs. Frequency.*

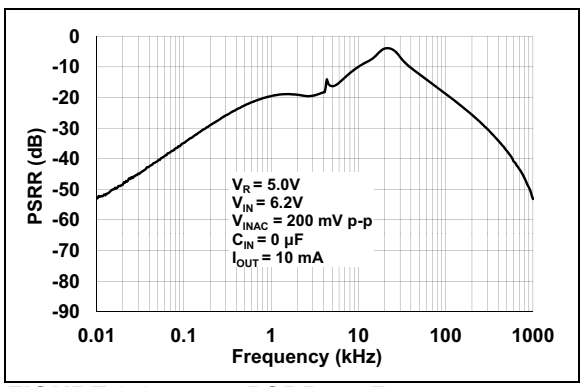


FIGURE 2-27: *PSRR vs. Frequency.*

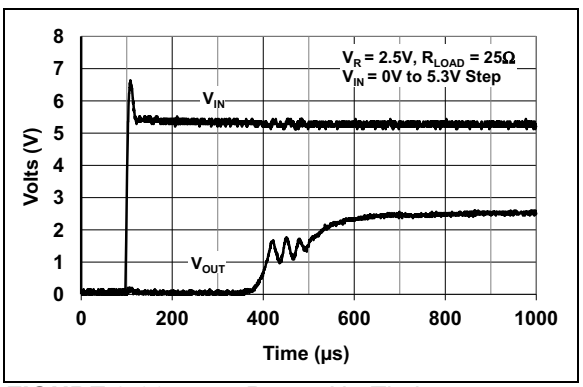


FIGURE 2-30: *Power Up Timing.*

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Note: Unless otherwise indicated: C_{OUT} = 1 µF Ceramic (X7R), C_{IN} = 1 µF Ceramic (X7R), I_L = 1 mA, T_A = +25°C, $V_{IN} = V_{OUT(MAX)} + V_{DROPOUT(MAX)}$ or 2.7V, whichever is greater.

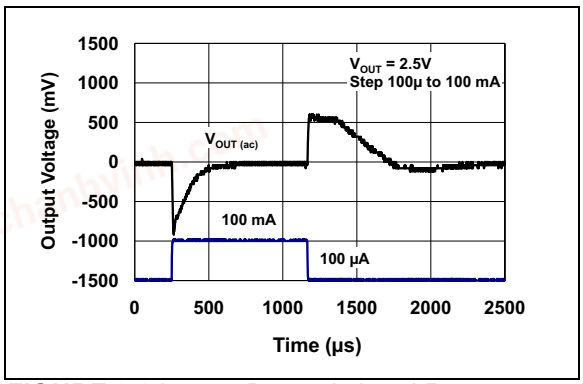


FIGURE 2-31: *Dynamic Load Response.*

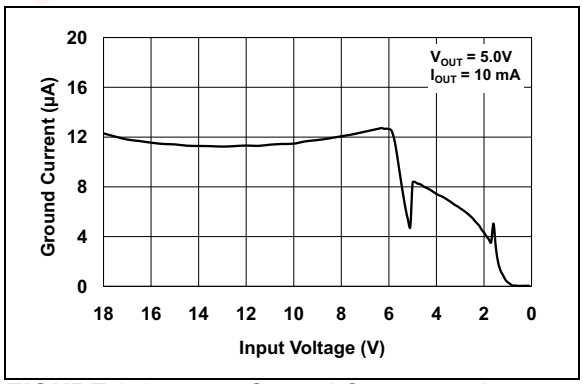


FIGURE 2-34: *Ground Current vs. Input Voltage.*

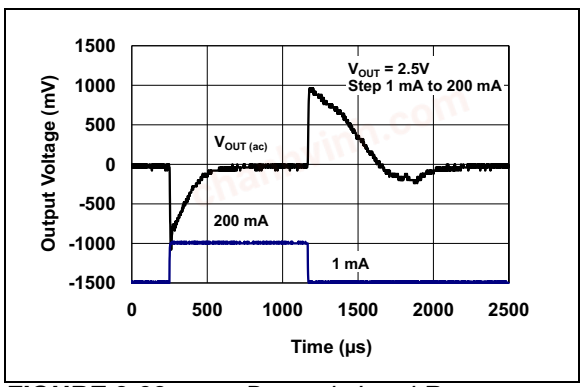


FIGURE 2-32: *Dynamic Load Response.*

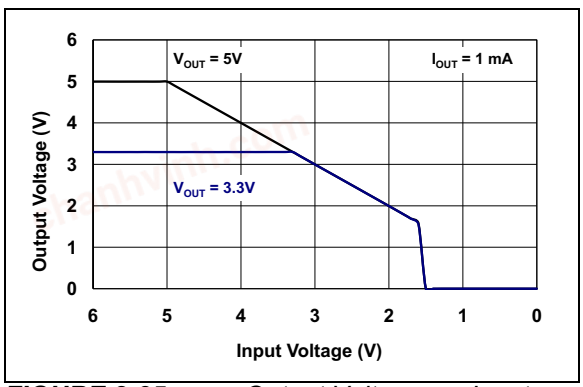


FIGURE 2-35: *Output Voltage vs. Input Voltage.*

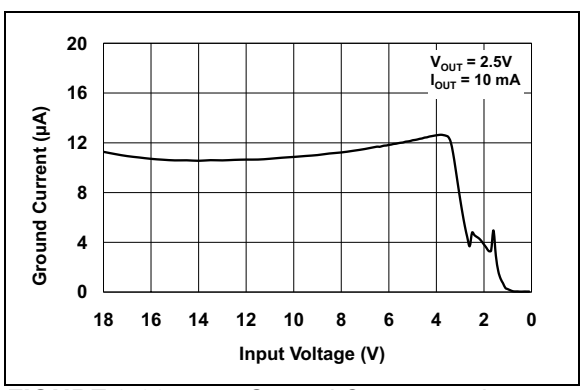


FIGURE 2-33: *Ground Current vs. Input Voltage.*

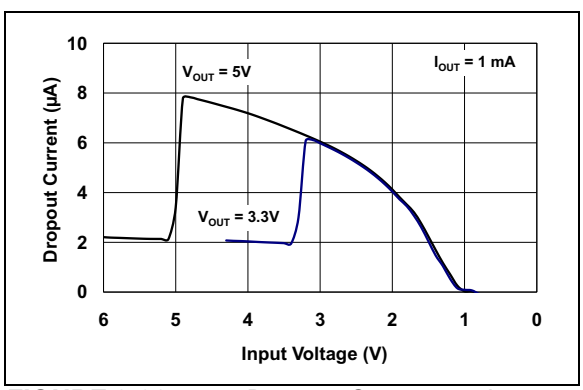


FIGURE 2-36: *Dropout Current vs. Input Voltage.*

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3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: MCP1703A PIN FUNCTION TABLE

2x3 DFN	SOT-223	SOT-23A	SOT-89	Name	Function
1	3	2	3	V_{OUT}	Regulated Voltage Output
2, 3, 5, 6, 7	—	—	—	NC	No Connection
4	2,Tab	1	1	GND	Ground Terminal
8	1	3	2,Tab	V_{IN}	Unregulated Supply Voltage
9	—	—	—	EP	Exposed Thermal Pad (EP); must be connected to VSS

3.1 Ground Terminal (GND)

Regulator ground. Tie GND to the negative side of the output and the negative side of the input capacitor. There is no high current and only the LDO bias current (2.0 µA typical) flows out of this pin. The LDO output regulation is referenced to this pin. Minimize voltage drops between this pin and the negative side of the load.

3.2 Regulated Output Voltage (V_{OUT})

Connect V_{OUT} to the positive side of the load and the positive terminal of the output capacitor. The positive side of the output capacitor should be physically located close to the LDO V_{OUT} pin as is practical. The current flowing out of this pin is equal to the DC load current.

3.3 Unregulated Input Voltage (V_{IN})

Connect V_{IN} to the input unregulated source voltage. Like all low dropout linear regulators, low source impedance is necessary for stable operation of the LDO. The amount of capacitance required to ensure low source impedance depends on the proximity of the input source capacitors or battery type. For most applications, 1 µF of capacitance ensures stable operation of the LDO circuit. The input capacitance requirement can be lowered for applications that have load currents below 100 mA. The type of capacitor used can be ceramic, tantalum or aluminum electrolytic. The low ESR characteristics of the ceramic yields better noise and PSRR performance at high-frequency.

3.4 Exposed Thermal Pad (EP)

An internal electrical connection between the Exposed Thermal Pad (EP) and the V_{SS} pin. They must be connected to the same potential on the Printed Circuit Board (PCB).

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4.0 DETAILED DESCRIPTION

4.1 Output Regulation

A portion of the LDO output voltage is fed back to the internal error amplifier and compared with the precision internal band gap reference. The error amplifier output adjusts the amount of current that flows through the P-Channel pass transistor, thus regulating the output voltage to the desired value. Any changes in input voltage or output current causes the error amplifier to respond and adjust the output voltage to the target voltage (see Figure 4-1).

4.2 Overcurrent

The MCP1703A internal circuitry monitors the amount of current flowing through the P-Channel pass transistor. In the event of a short-circuit or excessive output current, the MCP1703A turns off the P-Channel device for a short period, after which the LDO attempts to restart. If the excessive current remains, the cycle will repeat itself.

4.3 Overtemperature

The internal power dissipation within the LDO is a function of input-to-output voltage differential and load current. If the power dissipation within the LDO is excessive, the internal junction temperature rises above the typical shutdown threshold of 150°C. At that point, the LDO shuts down and begins to cool to the typical turn-on junction temperature of 130°C. If the power dissipation is low enough, the device will continue to cool and operate normally. If the power dissipation remains high, the thermal shutdown protection circuitry will again turn off the LDO, protecting it from catastrophic failure.

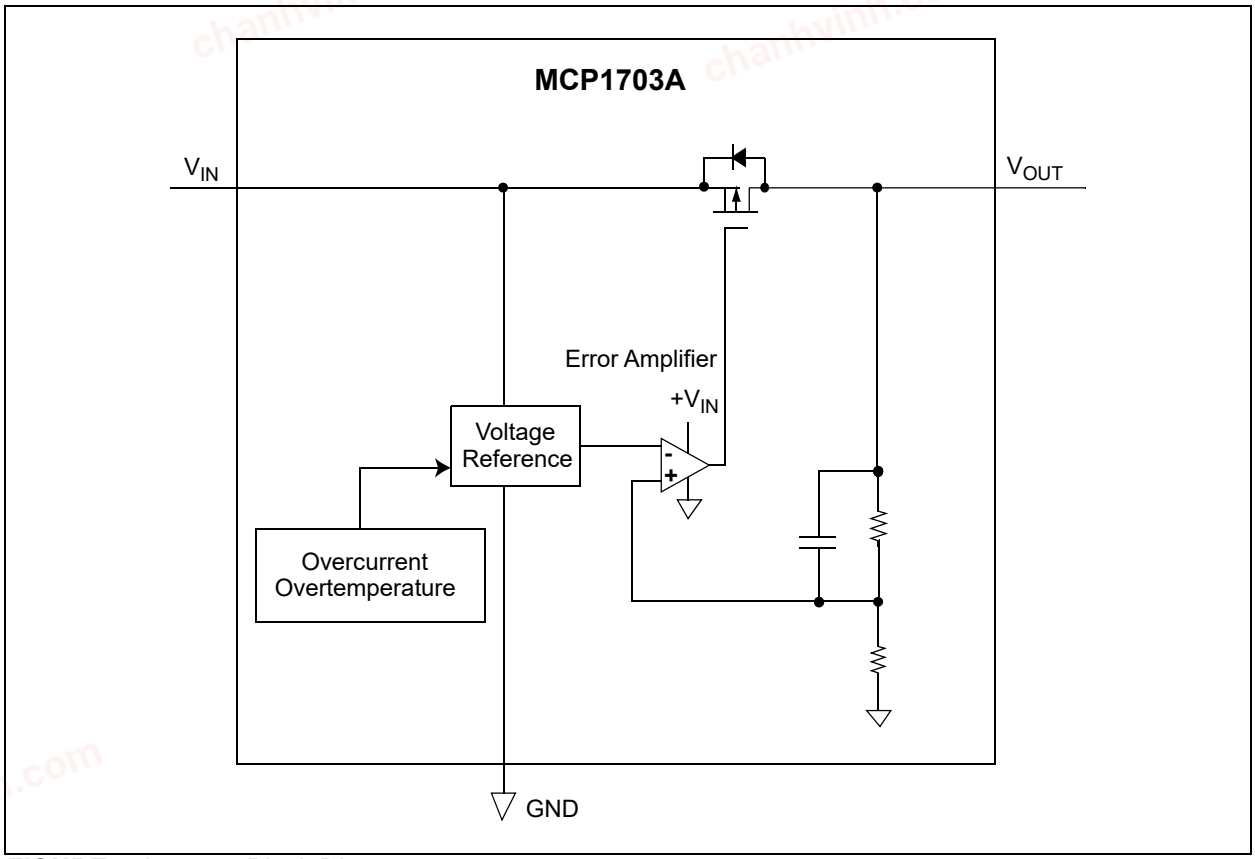


FIGURE 4-1: *Block Diagram.*

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5.0 FUNCTIONAL DESCRIPTION

The MCP1703A CMOS low dropout linear regulator is intended for applications that need the lowest current consumption while maintaining output voltage regulation. The operating continuous load range of the MCP1703A is from 0 mA to 250 mA ($V_R \geq 2.5V$). The input operating voltage ranges from 2.7V to 16.0V, making it capable of operating from two or more alkaline cells or single and multiple Li-Ion cell batteries.

5.1 Input

The input of the MCP1703A is connected to the source of the P-Channel PMOS pass transistor. As with all LDO circuits, a relatively low source impedance (10Ω) is needed to prevent the input impedance from causing the LDO to become unstable. The size and type of the capacitor needed depends heavily on the input source type (e.g., battery, power supply) and the output current range of the application. To ensure circuit stability, a 1 µF ceramic capacitor is sufficient for most applications up to 100 mA. Larger values can be used to improve circuit AC performance. The capacitance of the input capacitor should be equal to or greater than the capacitance of the selected output capacitor to ensure energy is available to keep the output capacitor charged during dynamic load changes.

5.2 Output

The maximum rated continuous output current for the MCP1703A is 250 mA ($V_R \geq 2.5V$). For applications where $V_R < 2.5V$, the maximum output current is 200 mA.

A minimum output capacitance of 1.0 µF is required for small signal stability in applications that have up to 250 mA output current capability. The capacitor type can be ceramic, tantalum or aluminum electrolytic. The Equivalent Series Resistance (ESR) range on the output capacitor ranges from 0Ω to 2.0Ω.

The output capacitor range for ceramic capacitors is 1 µF to 22 µF. Higher output capacitance values may be used for tantalum and electrolytic capacitors. Higher output capacitor values pull the pole of the LDO transfer function inward that results in higher phase shifts which in turn cause a lower crossover frequency. The circuit designer should verify the stability by applying line step and load step testing to their system when using capacitance values greater than 22 µF.

5.3 Output Rise Time

When powering up the internal reference output, the typical output rise time of 600 µs is controlled to prevent overshoot of the output voltage.

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6.0 APPLICATION CIRCUITS AND ISSUES

6.1 Typical Application

The MCP1703A is most commonly used as a voltage regulator. Its low quiescent current and low dropout voltage make it ideal for many battery-powered applications.

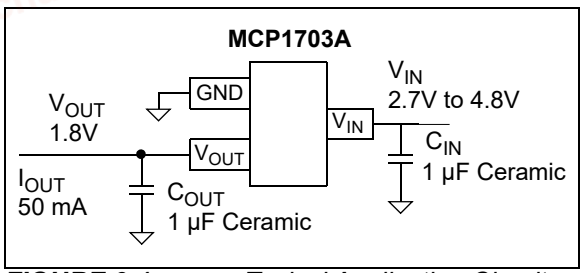


FIGURE 6-1: *Typical Application Circuit.*

6.1.1 APPLICATION INPUT CONDITIONS

Package Type	=	SOT-23A
Input Voltage Range	=	2.7V to 4.8V
V_{IN} maximum	=	4.8V
V_{OUT} typical	=	1.8V
I_{OUT}	=	50 mA maximum

6.2 Power Calculations

6.2.1 POWER DISSIPATION

The internal power dissipation of the MCP1703A is a function of input voltage, output voltage and output current. As a result of the quiescent current draw, the power dissipation is so low that it is insignificant (2.0 µA x V_{IN}). The following equation can be used to calculate the internal power dissipation of the LDO.

EQUATION 6-1:

$$P_{LDO} = (V_{IN(MAX)} - V_{OUT(MIN)}) \times I_{OUT(MAX)}$$

Where:

P_{LDO}	=	LDO Pass device internal power dissipation
$V_{IN(MAX)}$	=	Maximum input voltage
$V_{OUT(MIN)}$	=	LDO minimum output voltage

The maximum continuous operating junction temperature specified for the MCP1703A is +125°C. To estimate the internal junction temperature of the MCP1703A, the total internal power dissipation is multiplied by the thermal resistance from junction to ambient ($R\theta_{JA}$). The thermal resistance from junction to ambient for the SOT-23A pin package is estimated at 336°C/W.

EQUATION 6-2:

$$T_{J(MAX)} = P_{TOTAL} \times R\theta_{JA} + T_{A(MAX)}$$

Where:

$T_{J(MAX)}$	=	Maximum continuous junction temperature
P_{TOTAL}	=	Total device power dissipation
$R\theta_{JA}$	=	Thermal resistance from junction-to-ambient
$T_{A(MAX)}$	=	Maximum ambient temperature

The maximum power dissipation capability for a package can be calculated given the junction-to-ambient thermal resistance and the maximum ambient temperature for the application. The following equation can be used to determine the package maximum internal power dissipation.

EQUATION 6-3:

$$P_{D(MAX)} = \frac{(T_{J(MAX)} - T_{A(MAX)})}{R\theta_{JA}}$$

Where:

$P_{D(MAX)}$	=	Maximum device power dissipation
$T_{J(MAX)}$	=	Maximum continuous junction temperature
$T_{A(MAX)}$	=	Maximum ambient temperature
$R\theta_{JA}$	=	Thermal resistance from junction-to-ambient

EQUATION 6-4:

$$T_{J(RISE)} = P_{D(MAX)} \times R\theta_{JA}$$

Where:

$T_{J(RISE)}$	=	Rise in device junction temperature over the ambient temperature
P_{TOTAL}	=	Maximum device power dissipation
$R\theta_{JA}$	=	Thermal resistance from junction to ambient

EQUATION 6-5:

$$T_J = T_{J(RISE)} + T_A$$

Where:

T_J	=	Junction temperature
$T_{J(RISE)}$	=	Rise in device junction temperature over the ambient temperature
T_A	=	Ambient temperature

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6.3 Voltage Regulator

Internal power dissipation, junction temperature rise, junction temperature and maximum power dissipation are calculated in the following example. As a result of ground current, the power dissipation is small enough to be neglected.

6.3.1 POWER DISSIPATION EXAMPLE

Package

Package Type: SOT-23A

Input Voltage:

V_{IN} = 2.7V to 4.8V

LDO Output Voltages and Currents

V_{OUT} = 1.8V

I_{OUT} = 50 mA

Maximum Ambient Temperature

$T_{A(MAX)}$ = +40°C

Internal Power Dissipation

Internal Power dissipation is the product of the LDO output current multiplied by the voltage across the LDO
(V_{IN} to V_{OUT}).

$P_{LDO(MAX)} = (V_{IN(MAX)} - V_{OUT(MIN)}) \times I_{OUT(MAX)}$

P_{LDO} = (4.8V – (0.97 x 1.8V)) x 50 mA

P_{LDO} = 152.7 milli-Watts

Device Junction Temperature Rise

The internal junction temperature rise is a function of internal power dissipation and the thermal resistance from junction to ambient for the application. The thermal resistance from junction to ambient ($R\theta_{JA}$) is derived from an EIA/JEDEC standard for measuring thermal resistance for small surface mount packages. The EIA/JEDEC specification is JESD51-7, “High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages”. The standard describes the test method and board specifications for measuring the thermal resistance from junction to ambient. The actual thermal resistance for a particular application can vary depending on many factors, such as copper area and thickness. Refer to AN792, *“A Method to Determine How Much Power a SOT23 Can Dissipate in an Application”* (DS00792), for more information regarding this subject.

$T_{J(RISE)} = P_{TOTAL} \times R\theta_{JA}$

$T_{J(RISE)}$ = 152.7 milli-Watts x 336.0°C/Watt

$T_{J(RISE)}$ = 51.3°C

Junction Temperature Estimate

To estimate the internal junction temperature, the calculated temperature rise is added to the ambient or offset temperature. For this example, the worst-case junction temperature is estimated below.

$T_J = T_{J(RISE)} + T_{A(MAX)}$

T_J = 91.3°C

Maximum Package Power Dissipation at +40°C Ambient Temperature Assuming Minimal Copper Usage.

SOT-23A (336.0°C/Watt = $R\theta_{JA}$)

$P_{D(MAX)}$ = (+125°C – 40°C) / 336°C/W

$P_{D(MAX)}$ = 253 milli-Watts

SOT-89 (153.3°C/Watt = $R\theta_{JA}$)

$P_{D(MAX)}$ = (+125°C – 40°C) / 153.3°C/W

$P_{D(MAX)}$ = 0.554 Watts

SOT-223 (62.9°C/Watt = $R\theta_{JA}$)

$P_{D(MAX)}$ = (+125°C – 40°C) / 62.9°C/W

$P_{D(MAX)}$ = 1.35 Watts

6.4 Voltage Reference

The MCP1703A can be used not only as a regulator but also as a low quiescent current voltage reference. In many microcontroller applications, the initial accuracy of the reference can be calibrated using production test equipment or by using a ratio measurement. When the initial accuracy is calibrated, the thermal stability and line regulation tolerance are the only errors introduced by the MCP1703A LDO. The low-cost, low quiescent current and small ceramic output capacitor are all advantages when using the MCP1703A as a voltage reference.

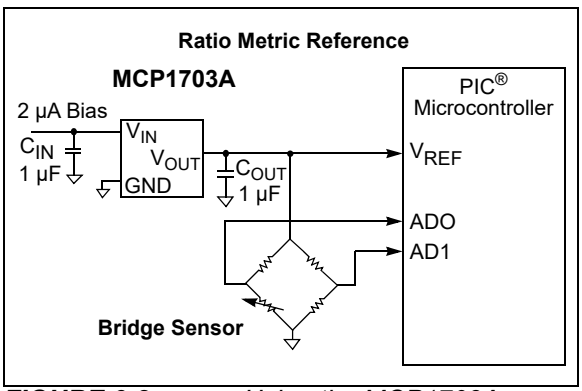


FIGURE 6-2: *Using the MCP1703A as a Voltage Reference.*

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6.5 Pulsed Load Applications

For some applications, there are pulsed load current events that may exceed the specified 250 mA maximum specification of the MCP1703A. The internal current limit of the MCP1703A prevents high peak load demands from causing non-recoverable damage. The 250 mA rating is a maximum average continuous rating. As long as the average current does not exceed 250 mA, pulsed higher load currents can be applied to the MCP1703A. The typical current limit for the MCP1703A is 500 mA (T_A = +25°C).

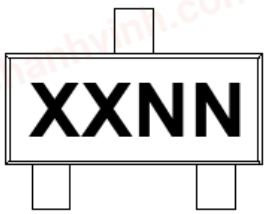
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7.0 PACKAGING INFORMATION

7.1 Package Marking Information

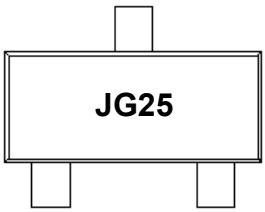
3-Lead SOT-23A



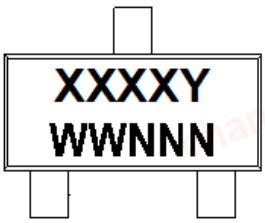
Standard Options for SOT-23A			
Symbol	**Voltage***	**Symbol**	**Voltage***
JG	1.2	JJ	3.0
JM	1.5	JK	3.3
JF	1.8	GG	3.5
JH	2.5	JP	4.0
JN	2.8	JL	5.0

* Custom output voltages available upon request. Contact your local Microchip sales office for more information.

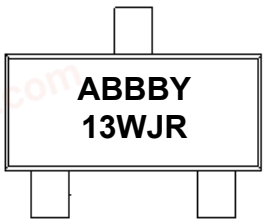
Example:



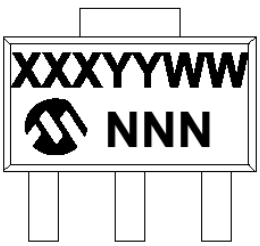
3-Lead SOT-23A
(only for 2.1V Standard variant)



Example:



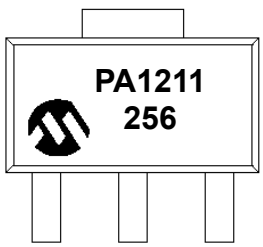
3-Lead SOT-89



Standard Options for SOT-89			
Symbol	**Voltage***	**Symbol**	**Voltage***
PA	1.2	PC	3.0
PF	1.5	PD	3.3
MZ	1.8	PH	4.0
PB	2.5	PE	5.0
PG	2.8	—	—

* Custom output voltages available upon request. Contact your local Microchip sales office for more information.

Example:



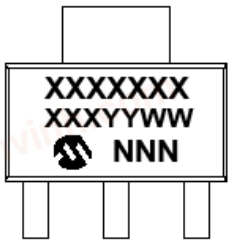
Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

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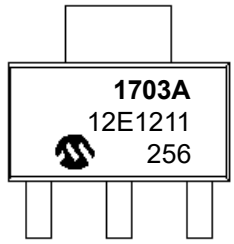
3-Lead SOT-223



Standard Options for SOT-223			
Symbol	**Voltage***	**Symbol**	**Voltage***
12	1.2	30	3.0
15	1.5	33	3.3
18	1.8	40	4.0
25	2.5	50	5.0
28	2.8	—	—
Custom			
33	3.3	—	—

* Custom output voltages available upon request. Contact your local Microchip sales office for more information.

Example:



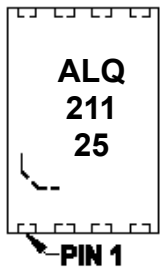
8-Lead DFN (2 x 3)



Standard Options for 8-Lead DFN (2 x 3)			
Symbol	**Voltage***	**Symbol**	**Voltage***
ALQ	1.2	ALV	3.0
ALR	1.5	ALW	3.3
ALS	1.8	ALX	4.0
ALT	2.5	ALY	5.0
ALU	2.8	—	—

* Custom output voltages available upon request. Contact your local Microchip sales office for more information.

Example:



Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

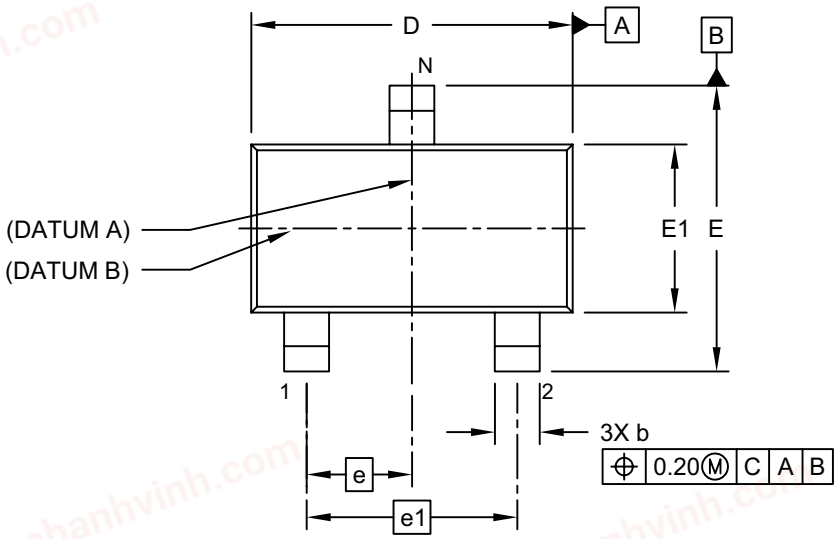
Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

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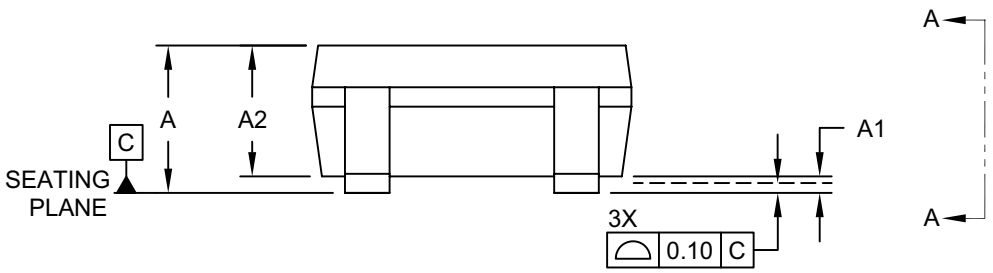
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3-Lead Plastic Small Outline Transistor (CB) [SOT-23A]

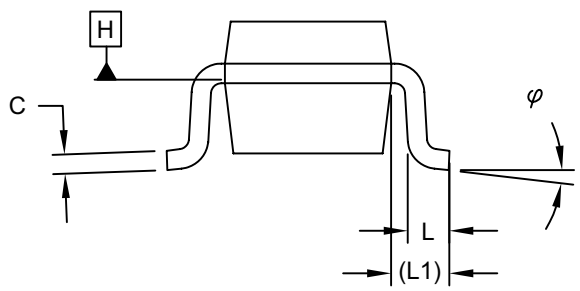
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



TOP VIEW



SIDE VIEW



VIEW A-A

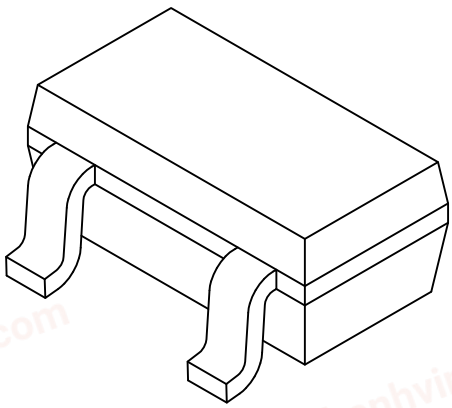
Microchip Technology Drawing C04-130 Rev C Sheet 1 of 2

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3-Lead Plastic Small Outline Transistor (CB) [SOT-23A]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		3	
Lead Pitch	e		0.95 BSC	
Outside Lead Pitch	e1		1.90 BSC	
Overall Height	A	0.90	-	1.45
Molded Package Thickness	A2	0.90	-	1.30
Standoff	A1	0.00	-	0.15
Overall Width	E	2.10	-	3.00
Molded Package Width	E1	1.20	-	1.80
Overall Length	D	2.70	-	3.10
Foot Length	L	0.15	-	0.60
Footprint	(L1)		0.54 REF	
Foot Angle	φ	0°	-	30°
Lead Thickness	c	0.09	-	0.26
Lead Width	b	0.30	-	0.51

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127mm per side.
2. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

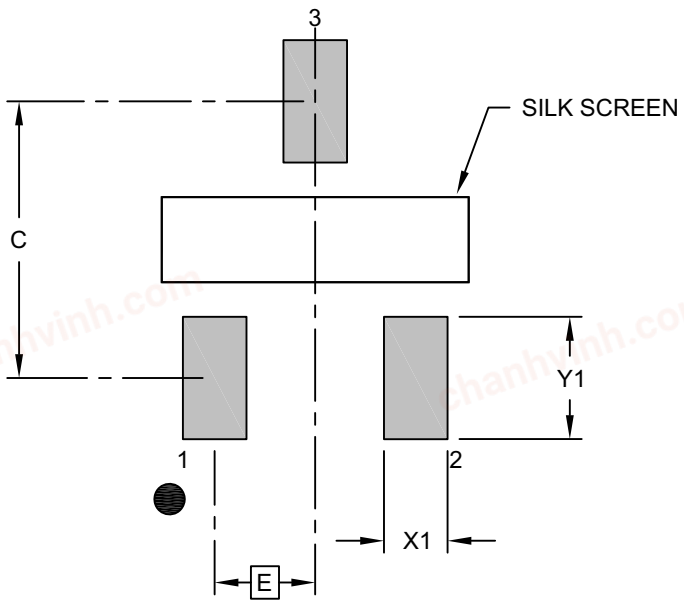
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3-Lead Plastic Small Outline Transistor (CB) [SOT-23A]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.95 BSC		
Contact Pad Spacing	C		2.60	
Contact Pad Width (X3)	X1			0.30
Contact Pad Length (X3)	Y1			1.15

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

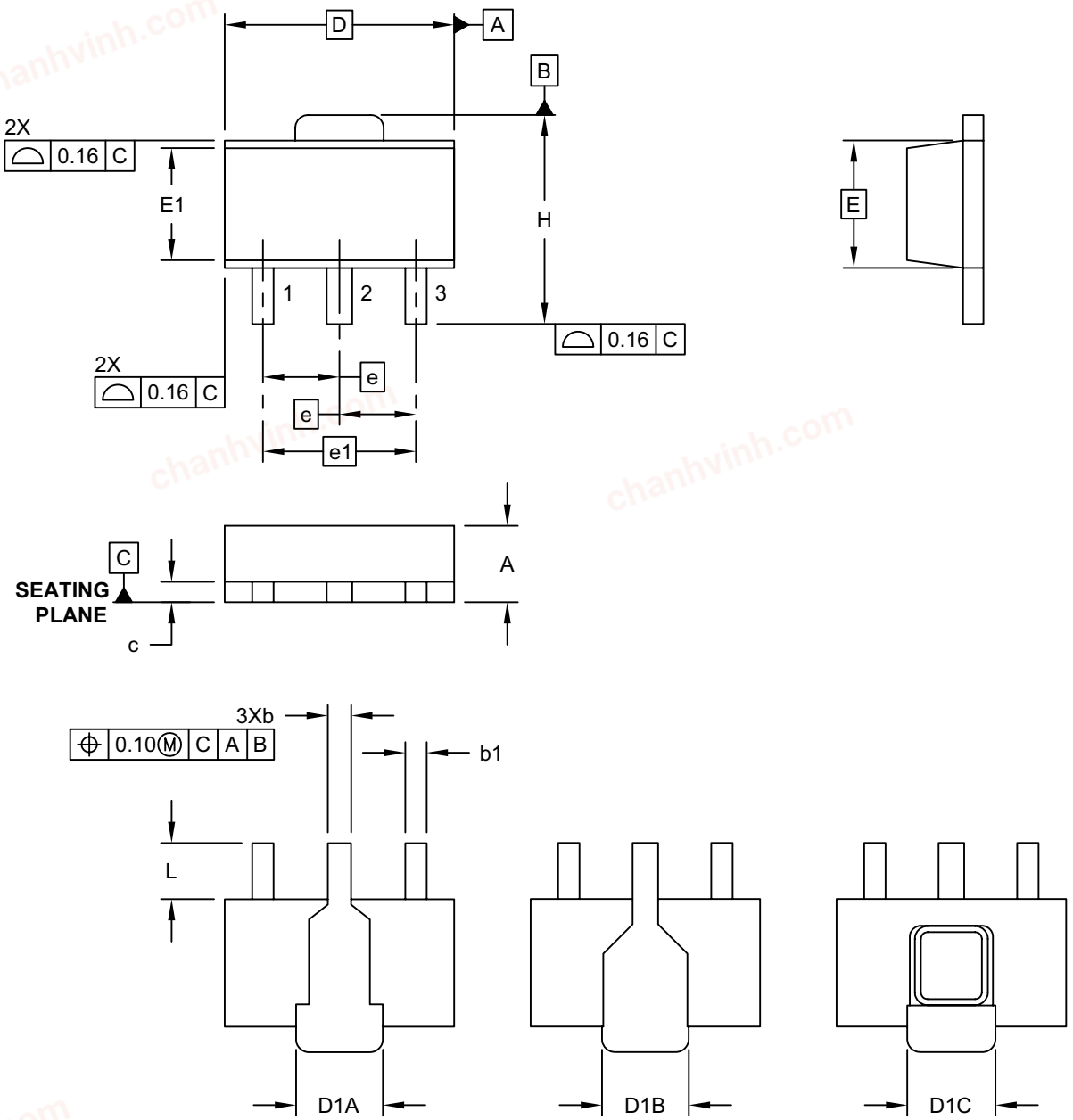
Microchip Technology Drawing C04-2130 Rev B

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3-Lead Plastic Small Outline Transistor (MB) - [SOT-89]

Note:	For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



OPTIONAL BACKSIDE PATTERNS — PARTS MAY BE SUPPLIED WITH ANY PATTERN SHOWN

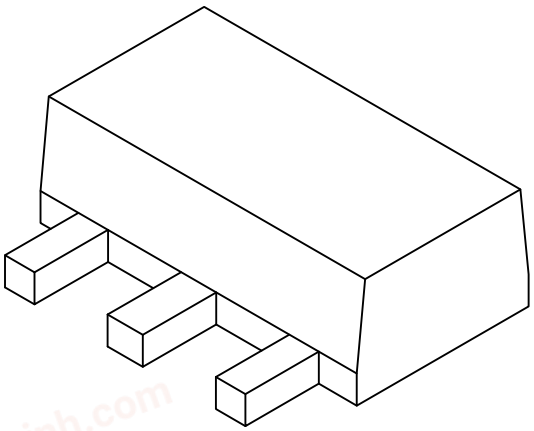
Microchip Technology Drawing C04-029C Sheet 1 of 2

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3-Lead Plastic Small Outline Transistor (MB) - [SOT-89]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Leads	N		3	
Pitch	e		1.50 BSC	
Outside Lead Pitch	e1		3.00 BSC	
Overall Height	A	1.40	1.50	1.60
Overall Width	H	3.94	4.10	4.25
Molded Package Width at Base	E		2.50 BSC	
Molded Package Width at Top	E1	2.13	2.20	2.29
Overall Length	D		4.50 BSC	
Tab Length (Option A)	D1A	1.63	1.73	1.83
Tab Length (Option B)	D1B	1.40	1.60	1.75
Tab Length (Option C)	D1C	1.62	1.73	1.83
Foot Length	L	0.79	1.10	1.20
Lead Thickness	c	0.35	0.40	0.44
Lead 2 Width	b	0.41	0.50	0.56
Leads 1 & 3 Width	b1	0.36	0.42	0.48

Notes:

1. Dimensions D and E do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127mm per side.
2. Dimensioning and tolerancing per ASME Y14.5M

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

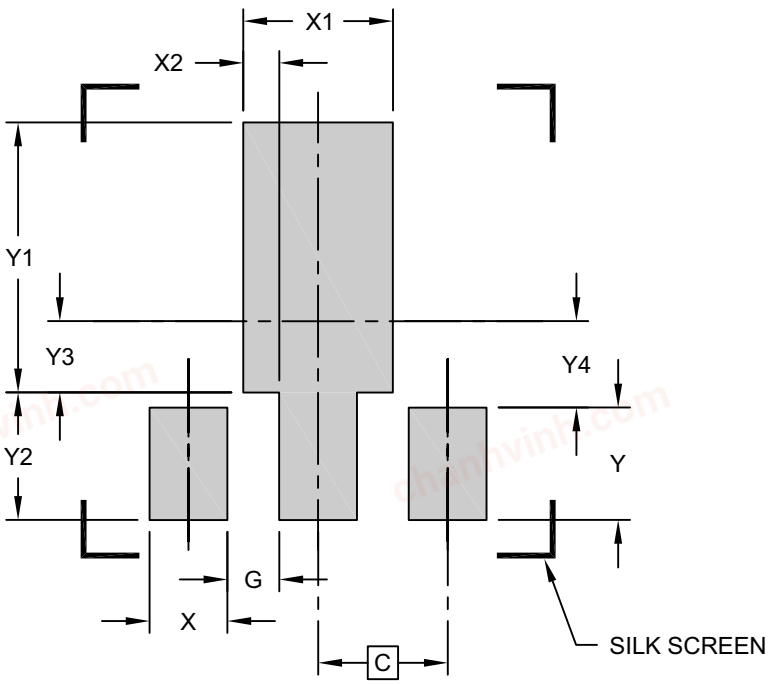
Microchip Technology Drawing C04-029C Sheet 2 of 2

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3-Lead Plastic Small Outline Transistor (MB) - [SOT-89]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units	MILLIMETERS		
Dimension Limits	MIN	NOM	MAX
C		1.50 (BSC)	
X (3 PLACES)		0.900	
X1		1.733	
X2 (2 PLACES)		0.416	
G (2 PLACES)		0.600	
Y (2 PLACES)		1.300	
Y1		3.125	
Y2		1.475	
Y3		0.825	
Y4		1.000	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

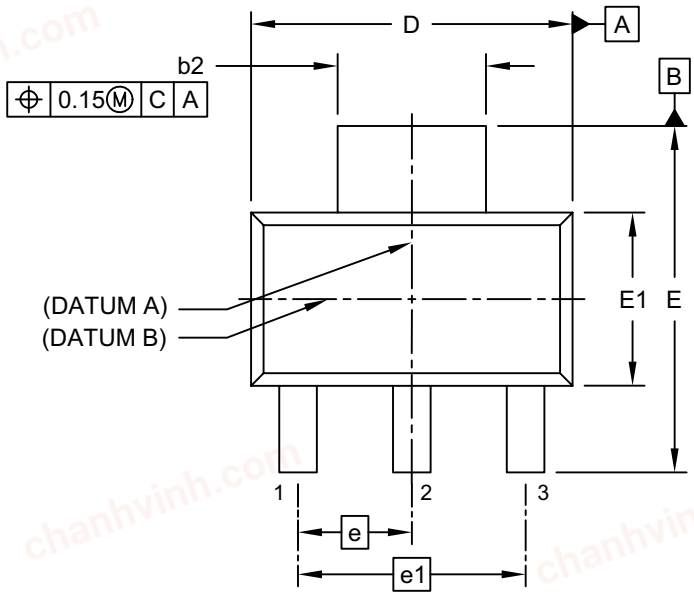
Microchip Technology Drawing C04-2029C

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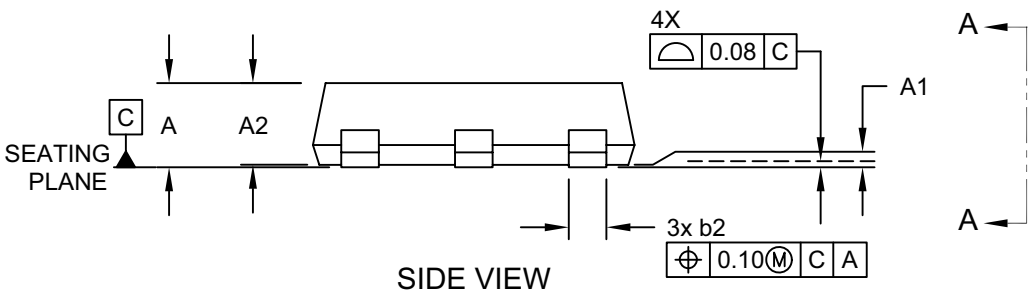
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3-Lead Plastic Small Outline Transistor (DB) [SOT-223]

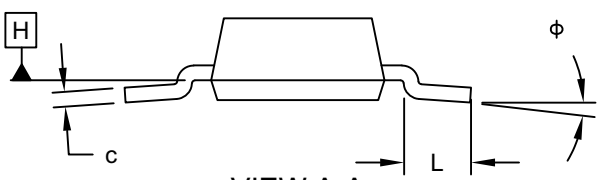
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



TOP VIEW



SIDE VIEW



VIEW A-A

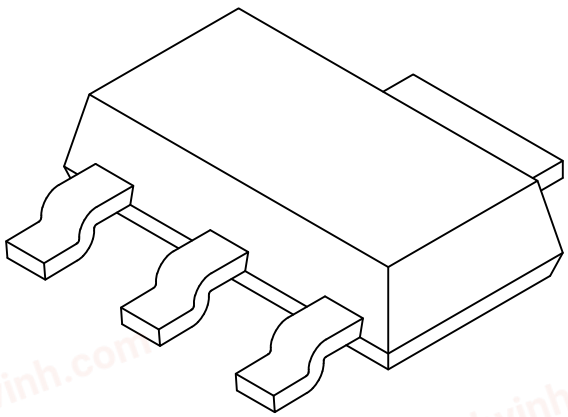
Microchip Technology Drawing C04-032 Rev D Sheet 1 of 2

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3-Lead Plastic Small Outline Transistor (DB) [SOT-223]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Leads	N		3	
Lead Pitch	e		2.30 BSC	
Outside lead pitch	e1		4.60 BSC	
Overall Height	A	-	-	1.80
Standoff	A1	0.02	-	0.10
Molded Package Height	A2	1.50	1.60	1.70
Overall Width	E	6.70	7.00	7.30
Molded Package Width	E1	3.30	3.50	3.70
Overall Length	D	6.30	6.50	6.70
Lead Thickness	c	0.23	0.30	0.35
Lead Width	b1	0.60	0.76	0.84
Tab Lead Width	b2	2.90	3.00	3.10
Foot Length	L	0.75	-	-
Lead Angle	ϕ	0°	-	10°

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127mm per side.
2. Dimensioning and tolerancing per ASME Y14.5M

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

   REF: Reference Dimension, usually without tolerance, for information purposes only.

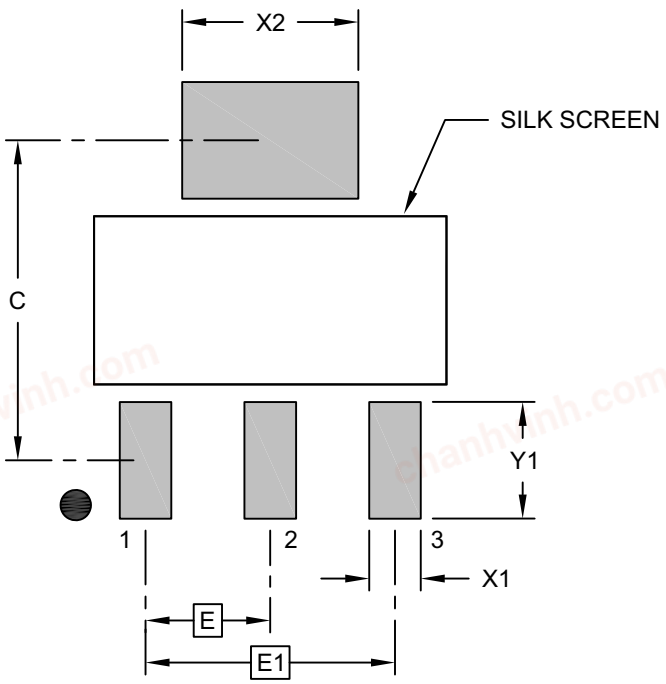
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3-Lead Plastic Small Outline Transistor (DB) [SOT-223]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		2.30 BSC	
Contact Pitch	E1		4.60 BSC	
Contact Pad Spacing	C		5.90	
Contact Pad Width (X3)	X1			0.95
Contact Pad Width	X2			3.25
Contact Pad Length (X4)	Y1			2.15

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

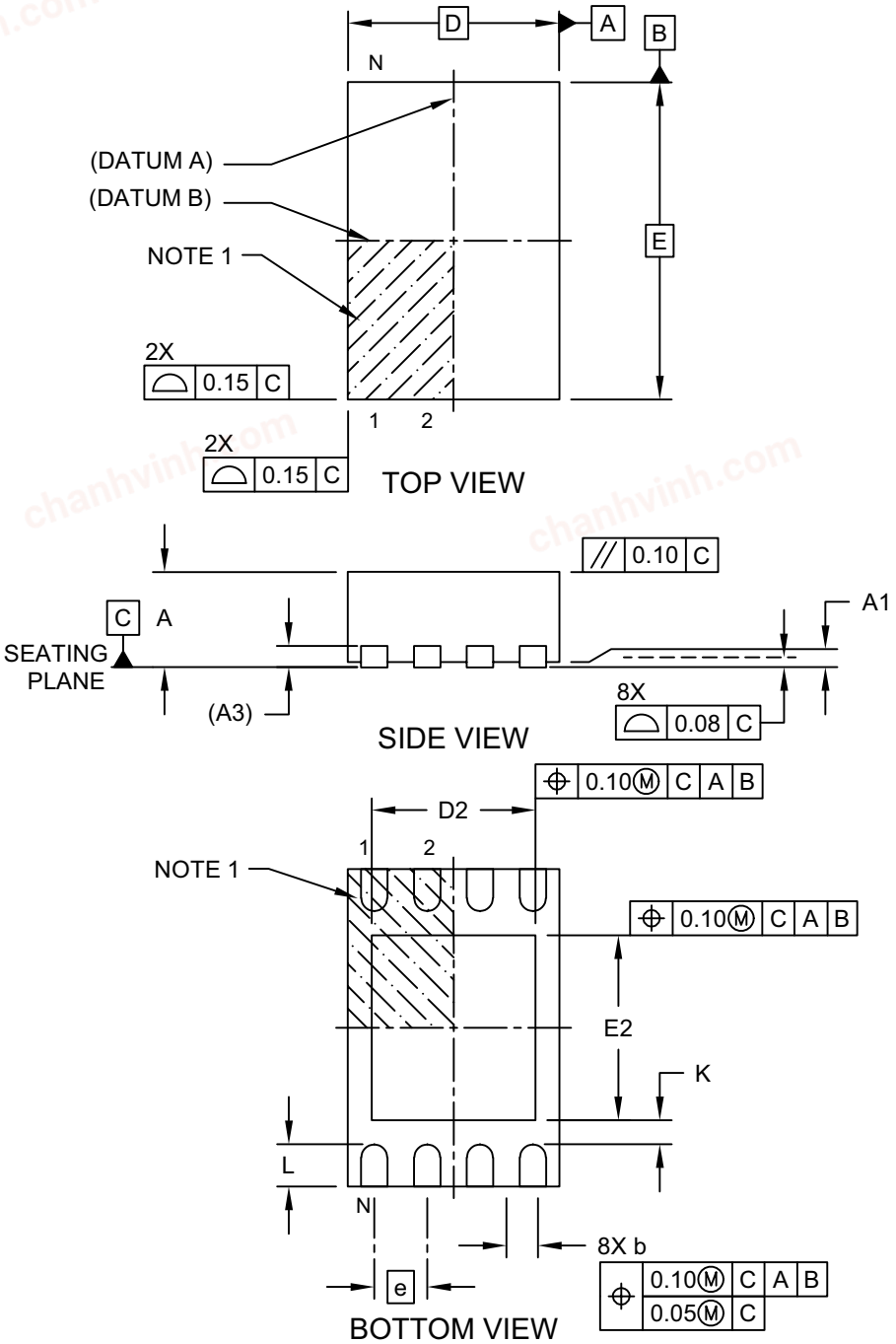
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8-Lead Plastic Dual Flat, No Lead Package (MC) - 2x3x1 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



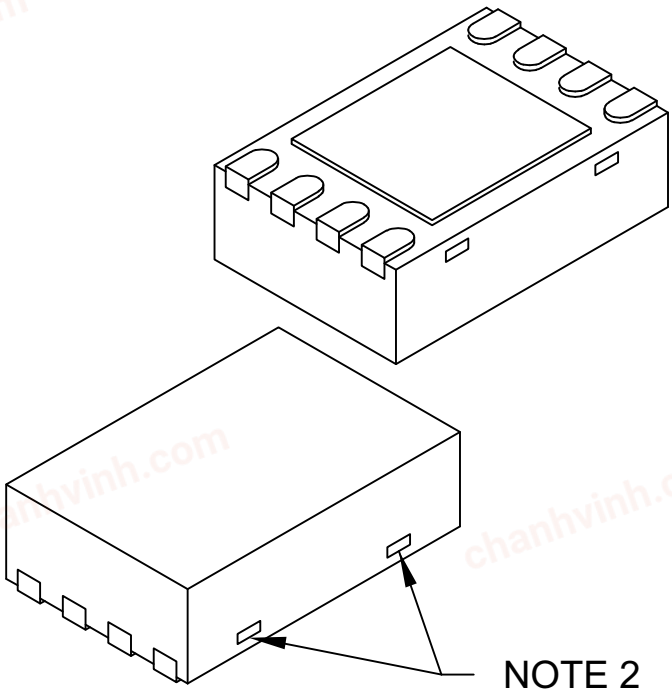
Microchip Technology Drawing C04-123 Rev E Sheet 1 of 2

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8-Lead Plastic Dual Flat, No Lead Package (MC) - 2x3x1 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		8	
Pitch	e		0.50 BSC	
Overall Height	A	0.80	0.90	1.00
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.20 REF	
Overall Length	D		2.00 BSC	
Exposed Pad Length	D2	1.30	-	1.55
Overall Width	E		3.00 BSC	
Exposed Pad Width	E2	1.50	-	1.75
Terminal Width	b	0.20	0.25	0.30
Terminal Length	L	0.30	0.40	0.50
Terminal-to-Exposed-Pad	K	0.20	-	-

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package may have one or more exposed tie bars at ends.
3. Package is saw singulated
4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.
REF: Reference Dimension, usually without tolerance, for information purposes only.

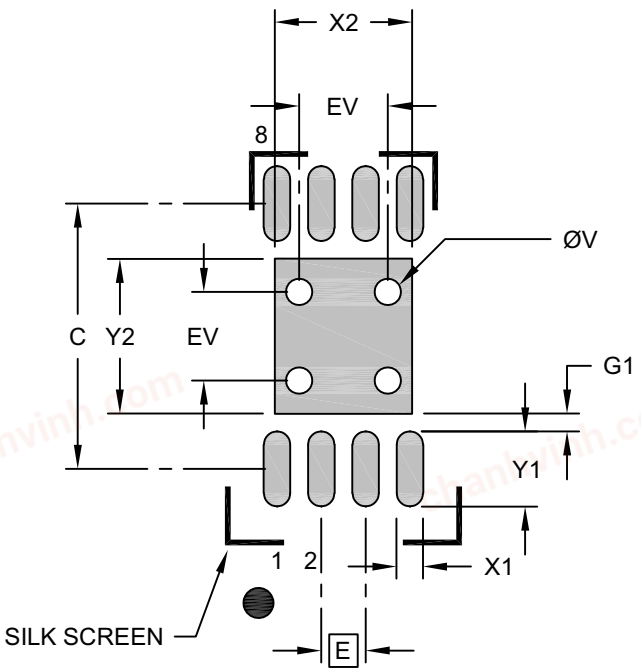
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8-Lead Plastic Dual Flat, No Lead Package (MC) - 2x3x1 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.50 BSC	
Optional Center Pad Width	X2			1.55
Optional Center Pad Length	Y2			1.75
Contact Pad Spacing	C		3.00	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.85
Contact Pad to Center Pad (X8)	G1	0.20		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

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APPENDIX A: REVISION HISTORY

Revision C (February 2023)

- Added information about the Automotive Qualification status of the device in **Section "Features"**.
- Added package marking for 2.1V standard variant and updated package drawings in **Section 7.0 "Packaging Information"**.
- Updated **Section "Product Identification System"**, with Automotive Qualified devices.
- Minor text and format changes throughout.

Revision B (September 2013)

The following is the list of modifications:

1. Updated Figure 2-10, Figure 2-16, Figure 2-17, Figure 2-27, Figure 2-28, Figure 2-29 and Figure 2-30.
2. Minor grammatical and editorial corrections.

Revision A (March 2012)

- Original Release of this Document.

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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	X	-XX	X	X	X	/XX	XXX
Device	Tape and Reel	Output Voltage	Feature Code	Tolerance	Temp.	Package	Qualification

Device: MCP1703A: 250 mA, 16V Low Quiescent Current LDO

Tape and Reel: T = Tape and Reel

Output Voltage*:
12 = 1.2V “Standard”
15 = 1.5V “Standard”
18 = 1.8V “Standard”
21 = 2.1V “Standard”
25 = 2.5V “Standard”
28 = 2.8V “Standard”
30 = 3.0V “Standard”
33 = 3.3V “Standard”
35 = 3.5V “Standard”
40 = 4.0V “Standard”
50 = 5.0V “Standard”
*Custom output voltages are available upon request. Contact your local Microchip sales office for more information.

Extra Feature Code: 0 = Fixed

Tolerance:
1 = 1.0% (Custom)
2 = 2.0% (Standard)

Temperature: E = -40°C to +125°C (Extended)

Package Type:
CB = Plastic Small Outline Transistor (SOT-23A), 3-lead
DB = Plastic Small Outline Transistor (SOT-223), 3-lead
MB = Plastic Small Outline Transistor (SOT-89), 3-lead
MC = Plastic Dual Flat, No Lead Package (DFN) - 2x3x0.9mm, 8-lead.

Qualification:**
(Blank) = Standard Part
VAO = Automotive AEC-Q100 Qualified
**Currently available VAO variants are:
MCP1703A-5002E/DBVAO, MCP1703AT-3302E/MBVAO, MCP1703AT-5002E/MBVAO, MCP1703AT-1802E/MBVAO, MCP1703AT-2502E/MCVAO, MCP1703AT-5002E/MCVAO, MCP1703AT-3302E/DBVAO, MCP1703AT-5002E/DBVAO, MCP1703AT-3302E/CBVAO, MCP1703AT-5002E/CBVAO
Contact your local Microchip sales office to request automotive qualified variants for other package types or voltage options.

Examples:

a) MCP1703AT-1202E/XX: Tape and Reel, 1.2V Low Quiescent LDO, Extended Temperature
b) MCP1703AT-1502E/XX: Tape and Reel, 1.5V Low Quiescent LDO, Extended Temperature
c) MCP1703AT-1802E/XX: Tape and Reel, 1.8V Low Quiescent LDO, Extended Temperature
d) MCP1703AT-2502E/XX: Tape and Reel, 2.5V Low Quiescent LDO, Extended Temperature
e) MCP1703AT-2802E/XX: Tape and Reel, 2.8V Low Quiescent LDO, Extended Temperature
f) MCP1703AT-3002E/XX: Tape and Reel, 3.0V Low Quiescent LDO, Extended Temperature
g) MCP1703AT-3302E/XX: Tape and Reel, 3.3V Low Quiescent LDO, Extended Temperature
h) MCP1703AT-4002E/XX: Tape and Reel, 4.0V Low Quiescent LDO, Extended Temperature
i) MCP1703AT-5002E/XX: Tape and Reel, 5.0V Low Quiescent LDO, Extended Temperature
j) MCP1703AT-1802E/XXVAO:Tape and Reel, 1.8V Low Quiescent LDO, Extended Temperature, Automotive Qualified
k) MCP1703AT-2502E/XXVAO:Tape and Reel, 2.5V Low Quiescent LDO, Extended Temperature, Automotive Qualified
l) MCP1703AT-3302E/XXVAO:Tape and Reel, 3.3V Low Quiescent LDO, Extended Temperature, Automotive Qualified
m)MCP1703AT-5002E/XXVAO:Tape and Reel, 5.0V Low Quiescent LDO, Extended Temperature, Automotive Qualified

XX = CB for 3-Lead SOT-23A package
= DB for 3-Lead SOT-223 package
= MB for 3-Lead SOT-89 package
= MC for 8-Lead DFN package

Note: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

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